

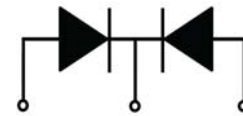
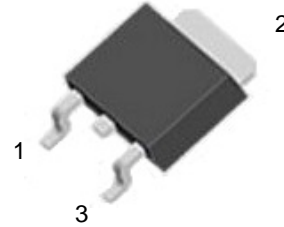


MBRD30100CT

Features:

- Low power loss, high efficiency.
High surge capacity
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- Metal silicon junction, majority carrier conduction.
- High current Capability, low forward voltage drop.
- Guard ring for over voltage protection.

TO-252



1.Anode 2.Cathode 3. Anode

Absolute Maximum Ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	100	V
Maximum RMS Voltage	V_{RMS}	70	V
Maximum DC Blocking Voltage	$V_{R(DC)}$	100	V
Maximum Average Forward Current	$I_{F(AV)}$	30	A
Peak Forward Surge Current:8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	350	A
Maximum Forward Voltage @IF=15A Tj=25°C	V_F	0.85	V
Maximum DC Reverse Current	I_R	Tj=25°C	0.1 mA
		Tj=125°C	20 mA
Maximum Operating Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-40~+150	°C



Typical Characteristics

RATING AND CHARACTERISTIC CURVES

FIG. 1- FORWARD CURRENT DERATING CURVE

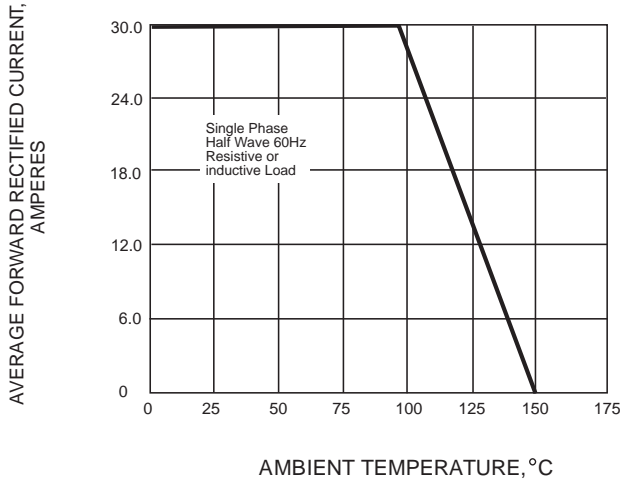


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

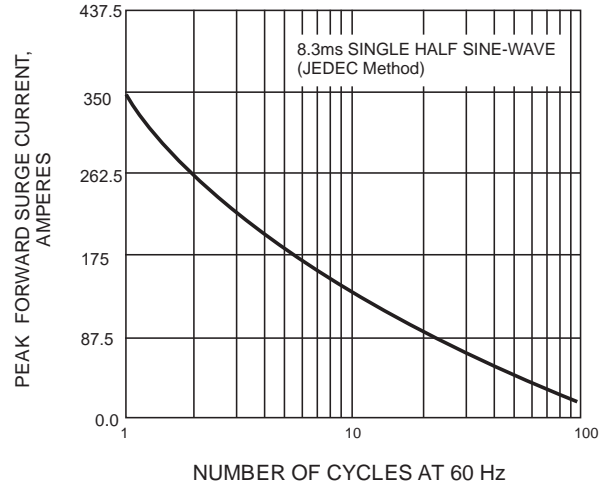


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

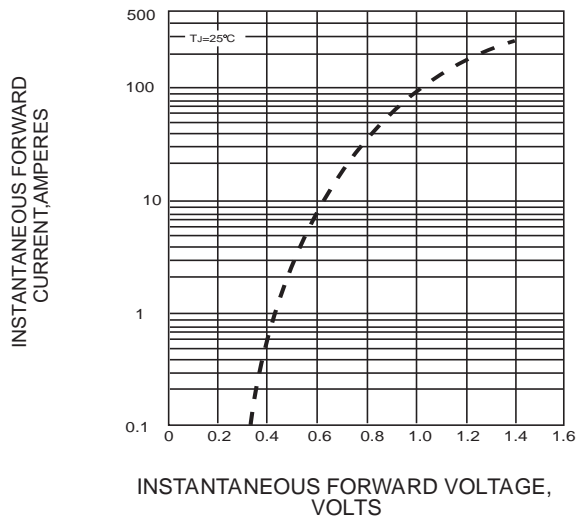
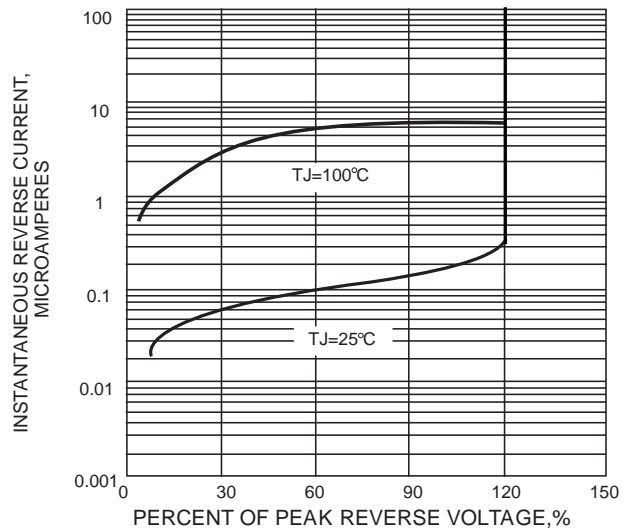


FIG. 4-TYPICAL REVERSE CHARACTERISTICS





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30A SCHOTTKY BARRIER RECTIFIER

Package Dimension

TO-252

Unit: mm

